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Journal of Alloys and Compounds

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Magnetic properties of new compounds RuMn₂Sn and RuMn₂Si

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ARTICLE INFO

Article history: Received 29 July 2011 Accepted 26 August 2011 Available online 6 September 2011

Keywords: RuMn₂Si RuMn₂Sn Ferrimagnetism Magnetic moment Curie temperature Spin-glass

ABSTRACT

New compounds $RuMn_2Z$ (Z=Si, Sn) have been synthesized. X-ray diffraction measurements have confirmed that $RuMn_2Z$ (Z=Si, Sn) crystallizes in a Heusler-like cubic structure. The lattice parameters of $RuMn_2Si$ and $RuMn_2Sn$ at room temperature are estimated to be 5.8260 Å and 6.2195 Å, respectively. Magnetization measurements have been carried out in fields up to 50 kOe for $RuMn_2Z$ (Z=Si, Sn). Furthermore, the temperature dependence of initial permeability of $RuMn_2Sn$ has been studied. $RuMn_2Sn$ shows ferrimagnetic behavior. The spontaneous magnetic moment at 5 K and the Curie temperature of $RuMn_2Sn$ are found to be of $1.68 \mu_B/f.u.$ and $272.1 \, K$, respectively. $RuMn_2Si$ exhibits spin-glass-like behavior with a freezing temperature estimated to be about 50 K.

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1. Introduction

Ferromagnetic shape memory alloys (FSMAs) with the L2₁ structure have attracted much attention due to their potential application as smart materials [1,2]. They show a large magneticfield-induced strain by the rearrangement of twin variants in the martensite phase [3]. Until now, several candidates for FSMAs have been reported. Among them, the stoichiometric Heusler alloy Ni₂MnGa is the most studied system. Ni₂MnGa has the cubic L2₁ Heusler structure at room temperature and orders ferromagnetically at a Curie temperature of 365 K. On cooling below a martensitic transition temperature of about 200 K, a superstructure forms [4]. A number of investigations on Ni-Mn-Ga FSMAs have been described in the literature because the Curie temperature and the martensitic transition temperature can be tuned by changing the composition of the constituent elements. Topics relating to Ni-Mn-Ga FSMAs have been reviewed by Entel et al. [5] and Brown et al. [6] in recent articles.

Recently, Liu et al. synthesized a new compound NiMn₂Ga which carries a magnetic moment of about 1.4 μ_B /f.u. at 5 K [7]. The Curie temperature was found to be 588 K [7]. Furthermore, they reported that NiMn₂Ga exhibits a martensitic transition around room temperature with a large hysteresis up to 50 K and a lattice distortion as large as 21.3%. They also observed an excellent two-way shape memory behavior with a strain of 1.7% in a single

crystal. Both experimental and theoretical studies made clear that NiMn₂Ga crystallizes in the Hg₂CuTi-type structure (space group $F\bar{4}3m$), which is different from the $L2_1$ structure with $Fm\bar{3}m$ space group [8]. Simultaneously, Barman et al. discussed the martensitic transition, ferrimagnetism and Fermi surface nesting using a firstprinciples calculation [9.10]. Liu et al. investigated theoretically and experimentally the electronic structures and magnetic properties of $CoMn_2Z$ (Z = Al, Ga, In, Si, Ge, Sn and Sb) compounds [11]. It was predicted that the compounds with Z=Al, Si, Ge, Sn and Sb are half-metallic ferrimagnets. Experimentally, they successfully synthesized the CoMn₂Z (Z = Al, Ga, In, Ge, Sn and Sb) compounds and confirmed that these compounds crystallize in the Hg₂CuTitype structure instead of the conventional L2₁ structure. However, there has been only a little amount of information on the magnetic moments and the exchange interactions for XMn_2Z (X = transition element: Z = s, p element) compounds. In this paper, the structural and magnetic properties of $RuMn_2Z(Z = Si, Sn)$ are examined experimentally to gain deeper insight into the magnetic moments and the exchange interactions of XMn₂Z alloys.

2. Experimental

For the preparation of the specimens, powdered ruthenium (99.9%), manganese (99.99%), silicon (99.9999%) and tin (99.99%) were mixed in the desired proportions and sealed in evacuated silica tubes. For the preparation of RuMn₂Sn, the mixture was first heated at $1000\,^\circ\text{C}$ for 3 days and then quenched into water. To achieve a high crystalline perfection, the reaction product was pulverized, carefully ground and heated again at $1050\,^\circ\text{C}$ for 3 days. The reaction product was then reheated to $1100\,^\circ\text{C}$ for 3 days and then quenched into water. For the preparation of RuMn₂Si, the mixture of constituents was first heated to $1100\,^\circ\text{C}$ for 3 days. Thereafter the reaction product was heated to $1100\,^\circ\text{C}$ for 3 days and then quenched into water. The

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observed X-ray diffraction patterns were analyzed using the Rietveld profile refinement program. The temperature dependence of the initial permeability was measured using an ac transformer method in which the primary and secondly coils were wound around a cylindrical sample of diameter ~ 1 mm and length ~ 10 mm. When an ac current of a constant amplitude flows in the primary coil, the voltage induced in the secondary coil is directly proportional to the initial permeability. Magnetization measurements on each sample were made in magnetic fields up to 50 kOe using a superconducting quantum interference device (SOUID) magnetometer.

3. Results and discussion

The Heusler L2₁-type structure is comprised of four interpenetrating fcc sublattices with A, B, C and D sites. The A, B, C and D sites are located at (0, 0, 0), (1/4, 1/4, 1/4), (1/2, 1/2, 1/2) and (3/4, 3/4, 3/4), respectively, as shown in Fig. 1. Fig. 2(a) shows the experimental X-ray diffraction pattern at room temperature for a powder sample of RuMn₂Sn. All the experimental diffraction lines can be indexed with the cubic structure. The sharp (220) peak confirms the presence of a single cubic phase. The lattice parameter a of RuMn₂Sn at room temperature was found to be 6.2195 Å. The pattern in Fig. 2(b) was calculated using the $L2_1$ structure and the experimental lattice parameter, with the A and C sites occupied by the Mn atoms, and B and D sites occupied by Ru and Sn atoms, respectively. We call this structure the $L2_1A$ -type. By exchanging the Mn atoms at the C sites with the Ru atoms at the B sites, the L2₁A-type structure changes into another ordered arrangement with a different superstructure. The prototype of this structure is the Hg₂CuTi compound which has the $F\bar{4}3m$ space group. Fig. 2(c) shows the X-ray powder diffraction pattern calculated by assuming the Hg₂CuTi-type structure. We call this structure the XA-type. The X-ray powder diffraction pattern of Fig. 2(d) was calculated by assuming that Mn atoms and Sn atoms occupy B sites and D sites, respectively, and that the other Mn atoms and Ru randomly

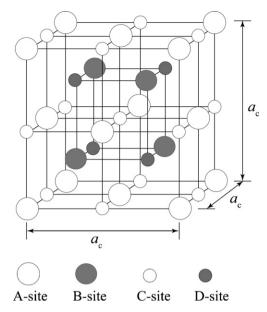


Fig. 1. Crystal structure of the Heusler-type alloy.

occupy the A and C sites. This leads to the $L2_1$ structure though the atomic arrangement is different from the $L2_1$ A-type structure. We call this structure the $L2_1$ B-type. The intensity I of different lattice diffraction line is proportional to the square of the structure factor, $F(h \, k \, l)^2$ in which h, k and l are the Miller indices. For Heusler alloys, $F(1 \, 1 \, 1)$, $F(2 \, 0 \, 0)$ and $F(3 \, 1 \, 1)$, etc. correspond to the order-dependent superlattice diffraction lines, whilst $F(2 \, 2 \, 0)$ is an order independent fundamental diffraction line. Therefore, the different superlattice structures can be distinguished by comparing the intensity ratio

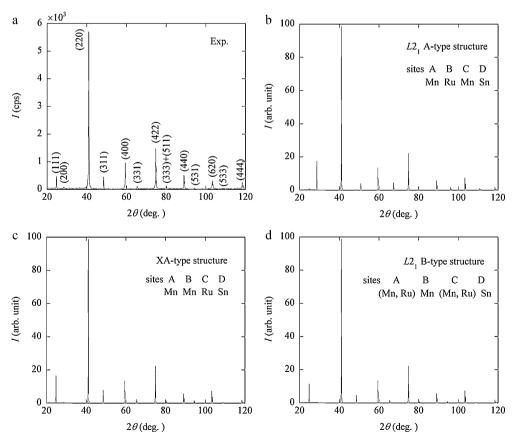


Fig. 2. Observed X-ray powder diffraction pattern at room temperature of $RuMn_2Sn$ (a). Calculated X-ray powder diffraction pattern of $RuMn_2Sn$ for the $L2_1A$ -type crystal structure (b), the XA-type crystal structure (c) and the $L2_1B$ -type crystal structure (d). The $L2_1A$, XA and $L2_1B$ -type crystal structures are explained in the text.

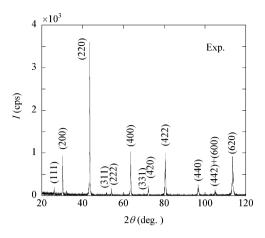


Fig. 3. Observed X-ray powder diffraction pattern at room temperature of RuMn₂Si.

of the different diffraction lines as I(111)/I(220). The experimental results of I(111)/I(220), I(200)/I(220) and I(311)/I(220) are in good agreement with those calculated for the L2₁B- or XA-type structure as shown in Fig. 2(c) and (d). It should be noted that the values of I(111)/I(220) etc. are nearly comparable for the $L2_1B$ and XA-type structure. Fig. 3 shows the experimental X-ray diffraction pattern at room temperature for a powder sample of RuMn₂Si. Most experimental diffraction lines were indexed using the fcc cubic structure consistent with RuMn₂Si also having the L2₁B- or XA-type structure. The lattice parameter a at room temperature of RuMn₂Si was estimated to be 5.8260 Å. Liu et al. reported that NiMn₂Ga crystallizes in the XA-type structure [8] but they did not consider the possibility of L2₁B order in their analysis of the X-ray powder diffraction pattern. Recently, Brown et al. carried out high resolution neutron diffraction measurements on NiMn₂Ga [12]. They showed that the austenite phase of NiMn₂Ga does not crystallize in the XA-type atomic order proposed on the basis of the X-ray measurements, but in the L2₁B-type crystal structure. Neutron diffraction measurements will also be necessary to establish the crystal structure of $RuMn_2Z$ (Z = Si, Sn).

The magnetization curve at $5 \, \text{K}$ for $\text{RuMn}_2 \text{Sn}$ is shown in Fig. 4. The magnetization M at $5 \, \text{K}$ is saturated in a field of about $5 \, \text{kOe}$, indicating that the magnetocrystalline anisotropy energy of $\text{RuMn}_2 \text{Sn}$ is small. The spontaneous magnetization at $5 \, \text{K}$ for $\text{RuMn}_2 \text{Sn}$ was determined by the linear extrapolation to H/M = 0 of the M^2 versus H/M curve. The magnetic moment was deduced from the value of the spontaneous magnetization at $5 \, \text{K}$ and was found

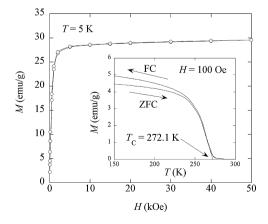


Fig. 4. Magnetization curve at $5 \, \text{K}$ of $\text{RuMn}_2 \text{Sn}$. The inset shows temperature dependence of the magnetization M at $100 \, \text{Oe}$ for $\text{RuMn}_2 \text{Sn}$. The arrows with ZFC and FC along the curves show the zero-field-cooling and field-cooling processes, respectively.

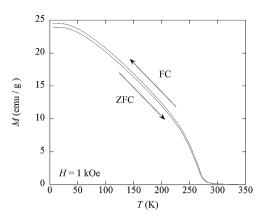


Fig. 5. Temperature dependence of the magnetization M at 1 kOe of RuMn₂Sn. The arrows with ZFC and FC along the curves show the zero-field-cooling and field-cooling processes, respectively.

to be $1.68 \mu_B/f.u.$ It should be noted that the magnetic moment per formula unit at 5 K of NiMn₂Ga has a similar value of about $1.4 \mu_B$ [7]. The inset in Fig. 4 shows the temperature dependence of the magnetization M at 100 Oe for RuMn₂Sn. As shown in the figure, M decreases rapidly just below T_C and takes a nearly constant value with further rise in temperature. A linear extrapolation of these two ranges was used to obtain a point of intersection which was taken to define the Curie temperature. Using this method the Curie temperature T_C of RuMn₂Sn was found to be 272.1 K. Fig. 5 shows the temperature dependence of the magnetization M in a field of H = 1 kOe for RuMn₂Sn. In a zero-field-cooled process (ZFC), a sample was first cooled to 5 K from room temperature under zero magnetic field; at this temperature the magnetic field H (=1 kOe) was applied and the magnetization was measured at this constant field with increasing temperature up to 400 K. Then, without removing the external field, the magnetization measurement was made on decreasing temperature, i.e., field-cooled (FC). The behavior of M(T) for RuMn₂Sn is that of a typical ferrimagnet predicted by molecular field theory on the basis of a localized model [13].

 $Ru_2MnZ(Z = Si, Ge, Sn \text{ and } Sb)$ crystallize in the $L2_1A$ -type structure [14,15]. For $Ru_2MnZ(Z = Si, Ge, Sn \text{ and } Sb)$, the Ru atoms occupy the A and C sites whilst the Mn and Z atoms occupy the B and D sites, respectively. These compounds exhibit antiferromagnetic behavior with a Néel temperature that reaches room temperature. The results of the neutron diffraction measurements for Ru₂MnZ (Z=Ge, Sn, Sb) indicate that these compounds have an antiferromagnetic type II (AF II) spin structure [16,17]. The AF II spin structure is characterized by (111) planes in which the spins are aligned ferromagnetically with adjacent planes coupled antiferromagnetically. Moreover, neutron diffraction measurements on Ru_2MnZ (Z = Ge, Sn, Sb) have shown that only the Mn atoms carry a magnetic moment with a value of about 4 µ_B. In order to examine the magnetic properties of Ru₂MnZ (Z=Si, Ge, Sn, Sb), Ishida et al. have calculated the electronic structures [18]. They established the localized nature of the Mn moment in Ru_2MnZ (Z = Si, Ge, Sn, Sb). In the case of RuMn₂Sn, the excess Mn atoms (MnI) occupy the A and/or C sites as shown in Fig. 1 even if RuMn₂Sn crystallizes in L2₁B- or XA-type structure as mentioned above. We call Mn atoms on the B sublattice MnII. It is expected that the hybridization between the Ru and MnII states is stronger than that between the Ru and MnI 3d states in RuMn₂Sn because the nearest neighbor distance (≈2.7 Å) between the Ru and MnII atoms is shorter than that (\approx 3.1 Å) between the Ru and MnI atoms. The strong hybridization pulls the MnII 3d states below the Fermi energy $E_{\rm F}$, resulting in strong polarization and a larger moment of the MnII atoms compared to that of the MnI atoms. Recently, Barman et al. studied theoretically the electronic structure of NiMn₂Ga using the full

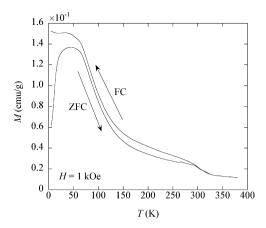


Fig. 6. Temperature dependence of the magnetization M at 1 kOe of RuMn₂Si. The arrows with ZFC and FC along the curves show the zero-field-cooling and field-cooling processes, respectively.

potential linearized augmented plane wave method (FPLAPW) [9]. They reported that the local magnetic moment in the austenite phase of NiMn₂Ga are -2.43, 3.2, 0.32 and 0.01 $\mu_B/f.u.$ for MnI, MnII, Ni and Ga, respectively. The difference between the MnI and MnII magnetic moments in NiMn₂Ga may be attributed to the difference in hybridization between the Ni and MnII 3d states, and the Ni and MnI 3d states. It is well known that exchange interactions in Mn-based alloys and compounds depend strongly on the Mn-Mn distance. Yamada et al. carried out a neutron diffraction measurement of α -Mn [19]. On the basis of the localized moment model, they discussed the dependence of Mn-Mn exchange interactions on the interatomic distance. Yamada's proposition shows that the nearest neighbor Mn-Mn exchange interaction has a minimum (negative) value around the nearest neighbor Mn–Mn distance R of 2.5 Å and increases with increasing R for R > 2.5 Å. Kanomata et al. suggested the interaction curve for the Heusler alloys containing Mn atoms [20-22]. Recently, Şaşıoğlu et al. studied theoretically the pressure dependence of exchange interactions in the ferromagnetic Heusler alloy Ni₂MnSn [23]. Empirical and theoretical interaction curves indicate that the Mn-Mn exchange interaction at short interatomic distance becomes negative. In the present study we observed a magnetic moment of 1.68 μ_B/f .u. at 5 K for RuMn₂Sn. This small magnetic moment per formula unit of RuMn₂Sn may be attributed to an antiferromagnetic coupling between the magnetic moments of MnI and MnII atoms, indicating that RuMn₂Sn is a ferrimagnet. This is consistent with the result of the temperature dependence of the magnetization for RuMn₂Sn shown in Fig. 5. Thus, the difference between MnI and MnII magnetic moments is a key to the magnetic moment per formula unit of $1.68 \mu_B$ for RuMn₂Sn.

Fig. 6 shows the temperature dependence of the magnetization in 1 kOe of RuMn₂Si for ZFC and FC processes. As shown in the figure, the magnetization for the ZFC process makes a broad maximum at about 50 K. With decreasing temperature, the magnetization decreases steeply. On the other hand, in the case of the FC process, the magnetization is almost constant below about 50 K. This behavior is typical for a spin-glass-like magnet with a freezing temperature T_f of about 50 K. Above T_f the magnetization decreases with increasing temperature but exhibits an anomaly around 300 K. Fig. 7 shows the magnetization curves of RuMn₂Si for $5 \le T \le 330$ K and in magnetic fields up to 50 kOe. As seen in the figure, the magnetization increases linearly with increasing applied field. From 5 K to 270 K a small ferromagnetic component can be observed in the magnetization curves. Thus, the anomaly at about 300 K in the M versus T curves of Fig. 6 is due to the contribution of a small amount of ferromagnetic impurity in RuMn₂Si. We determined the

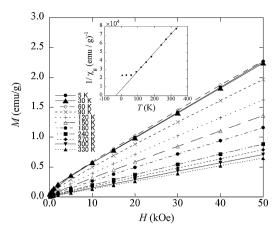


Fig. 7. Magnetization curves at various temperatures for RuMn₂Si. The inset shows the temperature dependence of the reciprocal susceptibility $1/\chi_g$ for RuMn₂Si.

temperature dependence of the magnetic susceptibility χ_g for RuMn₂Si from the slope of the magnetization curves in Fig. 7. The observed $1/\chi_g$ versus T curve is shown in the inset in Fig. 7. Above about 100 K the curve follows a Curie–Weiss law. From this result, the paramagnetic Curie temperature θ_p and the effective paramagnetic moment p_{eff} were determined to be -36 K and $3.0~\mu_B/f.u.$, respectively. In the case of RuMn₂Si, the value of the paramagnetic Curie temperature is negative, indicating that the antiferromagnetic interaction is a predominant exchange interaction. It is not clear why RuMn₂Si exhibits spin-glass-like behavior.

4. Summary

New compounds RuMn₂Si and RuMn₂Sn were synthesized in this study. X-ray measurements on RuMn₂Si and RuMn₂Sn have confirmed that these compounds have the Heusler-like cubic structure. The lattice constants of RuMn₂Si and RuMn₂Sn at room temperature are 5.8260 Å and 6.2195 Å, respectively. RuMn₂Sn shows the ferrimagnetic behavior. The Curie temperature and the magnetic moment per formula unit at 5 K of RuMn₂Sn are found to be 272.1 K and 1.68 μ_B , respectively. RuMn₂Si exhibits the spin-glass-like behavior. The freezing temperature is found to be about 50 K.

Acknowledgements

The authors would like to express sincere thanks to Professor S. Fujii at Kagoshima University for his helpful discussions. This work was partly supported by a grant based on the High-Tech Research Center Program for private universities from the Japan Ministry of Education, Culture, Sports, Science and Technology. This work was also supported by a Grant-in-Aid for Scientific Research (C) (Grant No. 21560693), provided by the Japan Society for the Promotion of Science.

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